

## **Performance and Test Methods**

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ltem		Performance	Test Methods and Conditions (In accordance with JIS C 5101-1)
		X7R Characteristics	
Capacitance		Within the tolerance	
Dissipation Factor		2.5% or less	Measurement Frequency Voltage  1kHz± 10% 1.0V± 10%  Heat-treated before measuring
Withstanding Voltage		No insulation breakdown and no failure.	Applied Voltage : 1∼5sec. Applied in silicon oil Charging & Discharging Current : 50mA max Test Voltage: Rated Voltage × 250%
Insulation Resistance		No less than $10,000M\Omega$	Applied Voltage : Rated Voltage Applied Time : 1min.
Adhesion Strength of Termination	Wire-Bonding	0.03N or more	Wire-bonded by $\varphi25\mu$ wire, then pull the wire in order to measure the strength
Temp. Cycle	Visual	No serious mechanical damage.	Room Temp. → Minimum Operation Temp. → Room Temp. → Maximum Operation Temp.
	Capacitance Change	±7.5% or less	
	Dissipation Factor (or Q)	Initial standard values must be satisfied.	3min. → 30min. →3min. → 30min.
	Insulation Resistance	Initial standard values must be satisfied.	Leaving a sample under the temperature of step 1-4 above in order to complete 1 cycle. The cycle is repeated 5 times.
	Withstanding Voltage	No insulation breakdown and no failure.	
Humidity Load Test	Visual	No serious mechanical damage.	Voltage Treatment  Test Temperature: 85±2°C  Relative Humidity: 85±3%RH  Test Voltage: 3.0  Test Time: 240-0,+24hours
	Capacitance Change	±12.5% or less	
	Dissipation Factor (or Q)	Less than double of the initial value	
	Insulation Resistance	No less than 1,000MΩ or 50MΩ $\cdot \mu$ F, whichever is smaller.	
Life Test (at Elevated Ambient Temp.)	Visual	No serious mechanical damage.	Voltage Treatment Test Temp. :125±3°C Test Voltage: Rated Voltage Test Time : 2000-0,+48hours
	Capacitance Change	±12.5% or less	
	Dissipation Factor (or Q)	Less than double of the initial value	
	Withstanding Voltage	No less than 1,000M $\Omega$ or 50M $\Omega$ $\cdot \mu F$ , whichever is smaller.	

Note1: Heat Treatment: The capacitor is heat-treated at 150+0/-10°C for 1 hour, then is left at room temperature for 48±4 hours.

Note2: Voltage Treatment: The capacitor is processed under the prescribed examination condition for 1 hour, then is left at room temperature for 48±4 hours.